P P SAVANI UNIVERSITY

First Semester of B. Tech. Examination January 2022

SESH1210 Applied Physics

25.01.2022, Tuesday

Time: 09:00 a.m. To 11:30 a.m.

Maximum Marks: 60

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- The question paper comprises of two sections.
- Section I and II must be attempted in same answer sheet.
- Make suitable assumptions and draw neat figures wherever required.
- 4. Use of scientific calculator is allowed.
- SECTION I Q-1 Answer the Following. [05] Give any two differences between matter waves and electromagnetic waves. (i) What are the Properties of sound absorbing material? (ii) Give the Miller indices for the planes given below: (iii) What do you mean by One dimensional nanomaterial? (iv) Give the full form of (I)SEM (II)TEM. (v) Derive the expression for energy levels of a particle enclosed in 1-D potential box of width [05] Q-2(a) "L" and infinite length. [04] Q-2 (b) (I) List any four Characteristics of Sound. [01] (II) Define Ultrasonic Wave. OR Q-2 (a) Derive time independent Schrödinger's equation. [05] Q-2 (b) (I) What is the wavelength of Ultrasonic wave of frequency 330 kHz at 0°C? [04] (II) What is sound Insulation? [01] Q-3 (a) (I) Explain Bragg's law for X-ray diffraction with an appropriate diagram. [04] (II) Define: Unit cell [01] Q - 3 (b) Explain the terms given below for nanomaterial: [05]

		(I) Increase in surface area to volume ratio	
		(II) Quantum confinement	
		OR	
	Q-3(a)	(I)State any four Properties of X-Rays.	[04]
		(II) What is the difference between Crystalline material and Amorphous material?	[01]
	Q-3(b)	Write applications of nano materials.	[05]
	Q - 4 Answer the Following (Attempt any one).		[05]
(i)		Find the kinetic energy and group velocity of an electron with de-Broglie wavelength of 0.2	
		nm.	
	(ii)	Explain: PVD (Physical vapour deposition technique) for the synthesis nano materials.	

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SECTION - II Answer the Following. Q-1

- Write the full form of LASER. (i)
- (ii) State Ohm's law.

[05]

(iii)	Explain the term: intrinsic semiconductor & extrinsic semiconductor	
(iv)	Define: Power factor	
(v)	In AC circuit the apparent power is always more than actual power. True / False?	
Q - 2 (a)	Using appropriate diagrams explain absorption, spontaneous emission and stimulated emission.	[05]
Q-2(b)	Write a short note on FET or Explain Construction, working and Output Characteristics of FET.	[05]
	OR	
Q - 2 (a)	Discuss the advantages of Optical fiber communication system over coaxial communication system.	[05]
Q-2(b)	What do you mean by Peak value, Average value and RMS Value of AC current or voltage? Explain with a proper diagram.	[05]
Q-3(a)	Obtain the formula of power factor for R-L-C series circuit and also discuss the cases When $X_L > X_C$, $X_C > X_L$ and $X_L = X_C$. Where $X_L = Inductive$ reactance and $X_C = Capacitive$ reactance	
Q-3 (b)	1. A 240 V, 50 Hz AC supply is applied a coil of 0.08 H inductance and 4 Ω resistance connected in series with a capacitor of 8 μ F. Calculate the Impedance and Circuit current.	[03]
	2. What is the difference between ordinary light and Laser beam?	[02]
	OR	[02]
Q-3(a)	Discuss the application of LASER in various field.	[05]
Q-3(b)	1. In a common base connection, current amplification factor is 0.9. If the emitter current is 1mA, determine the value of base current.	[03]
	Explain Active medium and Optical resonator	F007
Q-4	Answer the Following (Attempt any one).	[02]
		[05]
(i)	What is Unijunction Transistor (UJT)? Explain the Characteristic curve of Unijunction Transistor (UJT).	
(ii)	Explain Kirchhoff's Laws for junction and loop using appropriate diagram.	
